PTVSHC2EN15VU



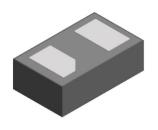
Uni-directional 15V High Capacitance TVS

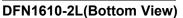
Description

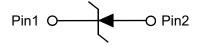
The PTVSHC2EN15VU Transient Voltage Suppressor is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDA's. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, lower operating voltage, lower clamping voltage and no device degradation when compared to MLVs.

The PTVSHC2EN15VU protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events.

The PTVSHC2EN15VU is available in a DFN1610-2L package with working voltages of 15 volt.



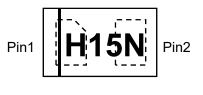


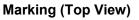


Circuit Diagram

Feature

- 1625W peak pulse power per line (t_P = 8/20µs)
- DFN1610-2L package
- Protect one I/O or power line
- Low clamping voltage
- ➢ RoHS compliant
- Transient protection for data lines to IEC 61000-4-2(ESD) ±30kV(air), ± 30kV(contact); IEC 61000-4-5 (Lightning) 65A (8/20us)





Applications

- Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- Notebooks, desktops and servers
- Portable instrumentation
- Cordless phones
- Digital cameras
- Peripherals
- MP4 players

Mechanical Characteristics

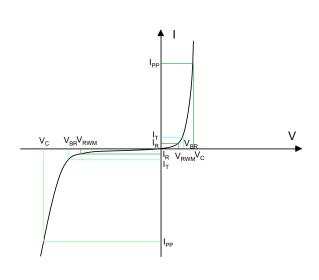
- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- Qualified max reflow temperature:260°C
- > Pure tin plating: $7 \sim 17$ um
- ➢ Pin flatness:≤3mil

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PTVSHC2EN15VU

Electronics Parameter

Symbol	Parameter			
V _{RWM}	Peak Reverse Working Voltage			
I _R	Reverse Leakage Current @ V _{RWM}			
V _{TRIG}	Reverse trigger Current			
V _{HOLD}	Reverse holding voltage			
I _T	Test Current			
I _{PP}	Maximum Reverse Peak Pulse Current			
V _c	Clamping Voltage @ I _{PP}			
P _{PP}	Peak Pulse Power			
CJ	Junction Capacitance			
I _F	Forward Current			
V _F	Forward Voltage @ I _F			



Electrical characteristics per line@25°C (unless otherwise specified)

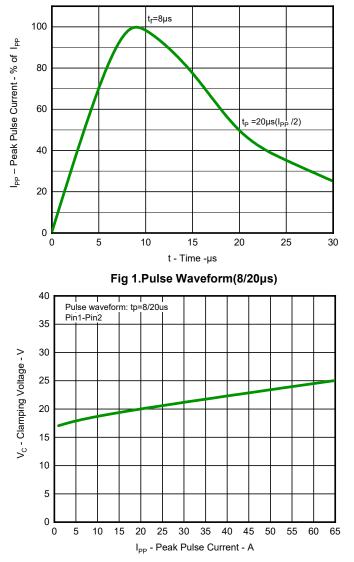
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units	
Peak Reverse Working Voltage	V _{RWM}	-	-	-	15	V	
Forward Voltage	V _F	I _F =10mA	-	0.75	-	V	
Breakdown Voltage	V _{BR}	I _t = 1mA	16	-	19	V	
Reverse Leakage Current	I _R	V _{RWM} = 15V	-	-	1.0	μA	
	V _c	I _{PP} = 10A,t _P = 8/20μs	-	19	22	v	
Clamping Voltage		I _{PP} = 65A,t _P = 8/20μs	-	25	28		
Junction Capacitance	CJ	V _R = 0V,f = 1MHz	-	400	600	pF	

Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Peak Pulse Power (t _P = 8/20µs)	P _{PP}	1625	W
Peak Pulse Current (t _P = 8/20µs)	I _{PP}	65	А
Lead Soldering Temperature	TL	260 (10 sec)	°C
Junction and Storage Temperature Range	T _{J,} T _{STG}	-55~+150	°C
ESD Protection-Contact Discharge	V _{ESD}	±30	kV
ESD Protection-Air Discharge	V _{ESD}	±30	kV

PTVSHC2EN15VU

Typical Characteristics





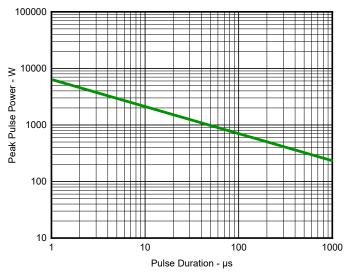
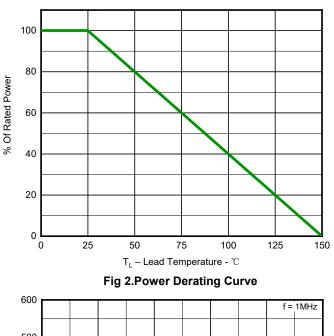


Fig 5. Non Repetitive Peak Pulse Power vs. Pulse time



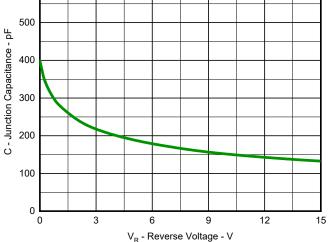


Fig 4. Capacitance vs. Reveres Voltage

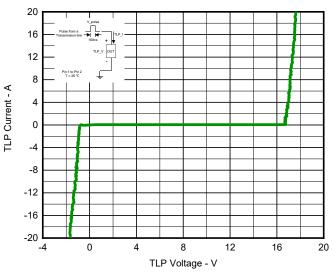
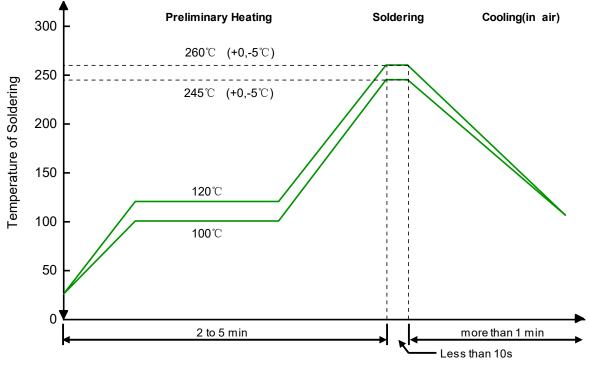


Fig 6. TLP Measurement

PTVSHC2EN15VU

Solder Reflow Recommendation



Remark: Pb free for 260°C; Pb for 245°C.

PCB Design

For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

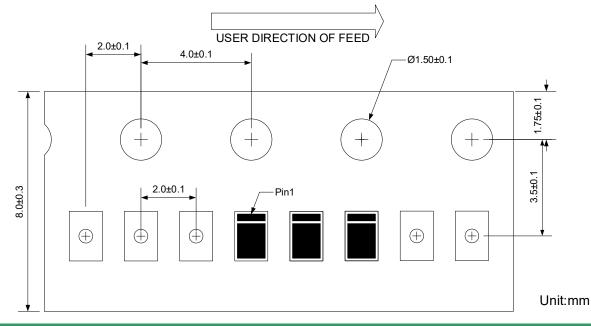
- > Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- > Do not make false economies and save copper for the ground connection.
- > Place via holes to ground as close as possible to the anode of the TVS diode.
- > Use as many via holes as possible for the ground connection.
- > Keep the length of via holes in mind! The longer the more inductance they will have.

Ordering information

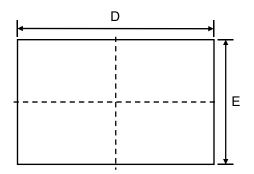
Device	Package	Reel	Shipping
PTVSHC2EN15VU	PTVSHC2EN15VU DFN1610-2L (Pb-Free)		10000 / Tape & Reel

PTVSHC2EN15VU

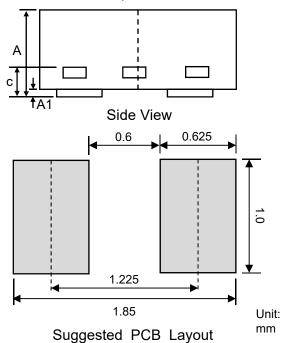
Load with information

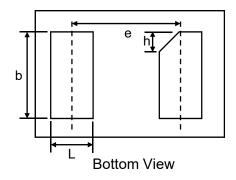


Product dimension (DFN1610-2L)









Dim	Millimeters		Inches		
	Min	Max	Min	Max	
А	0.40	0.60	0.016	0.024	
A1	0.00	0.05	0.000	0.002	
b	0.75	0.85	0.030	0.033	
с	0.05	0.20	0.002	0.008	
D	1.55	1.65	0.061	0.065	
E	0.95	1.05	0.037	0.041	
е	1.10 BSC		0.043 BSC		
L	0.35	0.45	0.014	0.018	
h	0.15	0.25	0.006	0.010	

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